


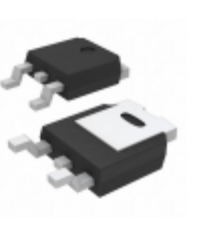
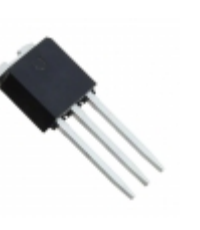
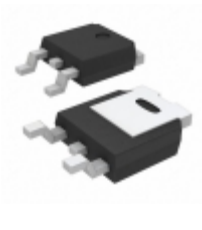
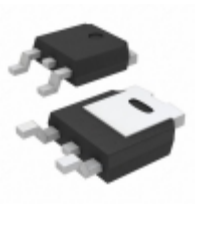


	<p><b>Hersteller-Teilenummer:</b> <a href="#">STD11NM50N</a></p>
	<p><b>Hersteller / Marke:</b> <a href="#">STMicroelectronics</a></p>
<p><b>Teil der Beschreibung:</b> MOSFET N-CH 500V 9A DPAK</p>	<p><b>Datenblätter:</b>  <a href="#">STD11NM50N.pdf</a></p>
<p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p>	<p><b>Lagerzustand:</b> New original, 60735 pcs Stock Available.</p>
<p><b>Lieferung von:</b> Hong Kong</p>	<p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">STD11NM50N</a>
Hersteller	<a href="#">STMicroelectronics</a>
Beschreibung	MOSFET N-CH 500V 9A DPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	60735 pcs Stock
Serie	MDmesh™ II
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	70W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.5A (Tc)
Rds On (Max) @ Id, Vgs	470 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	19nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	547pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)



















































STD11NM50N ist neu im Original, Suche STD11NM50N Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD11NM50N STMicroelectronics mit Garantie und Vertrauen. Anfrage STD11NM50N: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>STD11NM60N</b> STMicroelectronics MOSFET N-CH 600V 10A DPAK	 <b>STD11NM60ND</b> STMicroelectronics MOSFET N-CH 600V 10A DPAK	 <b>STD11N60M2-EP</b> STMicroelectronics N-CHANNEL 600 V, 0.550 OHM TYP.,	 <b>STD11NM60N-1</b> STMicroelectronics MOSFET N-CH 600V 10A I-PAK
 <b>STD11N60DM2</b> STMicroelectronics N-CHANNEL 600 V, 0.26 OHM TYP.,	 <b>STD11N65M2</b> STMicroelectronics MOSFET N-CH 650V 7A DPAK	 <b>STD11N65M5 11NM65</b> ST STD11N65M5 11NM65 ST	 <b>STD11NM65M5 11N65</b> TO-252 STD11NM65M5 11N65 TO-252

### heiße Teile

Mehr

 STD10NM50N	 STD10NM60N	 STD10NM60ND	 STD10NM65N	 STD10P10F6
 STD10P6F6	 STD10PF06	 STD10PF06-1	 STD10PF06L	 STD10PF06T4
 STD110N8F6	 STD110NH02LT4	 STD116GK08	 STD116GK08B	 STD116GK12
 STD116GK12B	 STD116GK14	 STD116GK14B	 STD116GK16	 STD116GK16B
 STD116GK18	 STD116GK18B	 STD11N50M2	 STD11N65M2	 STD11N65M5
 STD11NM60N	 STD11NM60ND	 STD120N4F6	 STD120N4LF6	 STD123SF
 STD123UF	 STD125GK16	 STD12L01	 STD12L01A	 STD12N05LT4
 STD12N06	 STD12N06L	 STD12N06LT4	 STD12N06T4	 STD12N10L
 STD12N10L-TR	 STD12N50M2	 STD12N60M2	 STD12N65M5	 STD12NE06
 STD12NE06L-TR	 STD12NE06LT4	 STD12NE06T4	 STD12NF06-1	 STD12NF06L-1

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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